

# RJK0305DPB-02

30V, 30A, 8.0mΩmax  
Silicon N Channel Power MOS FET  
Power Switching

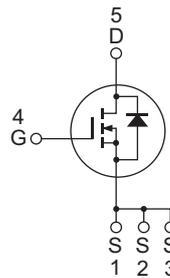
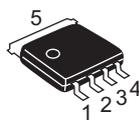
R07DS1245EJ0901  
(Previous: REJ03G1353-0900)  
Rev.9.01  
Jan 07, 2015

## Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance  
 $R_{DS(on)} = 6.7 \text{ m}\Omega$  typ. (at  $V_{GS} = 10 \text{ V}$ )
- Pb-free
- Halogen-free

## Outline

RENESAS Package code: PTZZ0005DA-A  
(Package name: LFPAK)



1, 2, 3 Source  
4 Gate  
5 Drain

## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	30	V
Gate to source voltage	$V_{GSS}$	+16/-12	V
Drain current	$I_D$	30	A
Drain peak current	$I_{D(pulse)}$ <sup>Note 1</sup>	120	A
Body-drain diode reverse drain current	$I_{DR}$	30	A
Avalanche current	$I_{AP}$ <sup>Note 2</sup>	10	A
Avalanche energy	$E_{AR}$ <sup>Note 2</sup>	10	mJ
Channel dissipation	$P_{ch}$ <sup>Note 3</sup>	45	W
Channel to Case Thermal Resistance	$\theta_{ch-C}$	2.78	$^\circ\text{C}/\text{W}$
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10 \mu\text{s}$ , duty cycle  $\leq 1\%$   
2. Value at  $T_{ch} = 25^\circ\text{C}$ ,  $R_g \geq 50 \Omega$   
3.  $T_c = 25^\circ\text{C}$

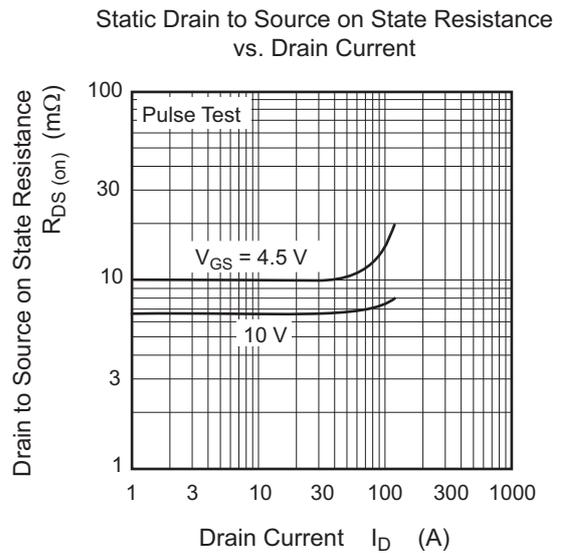
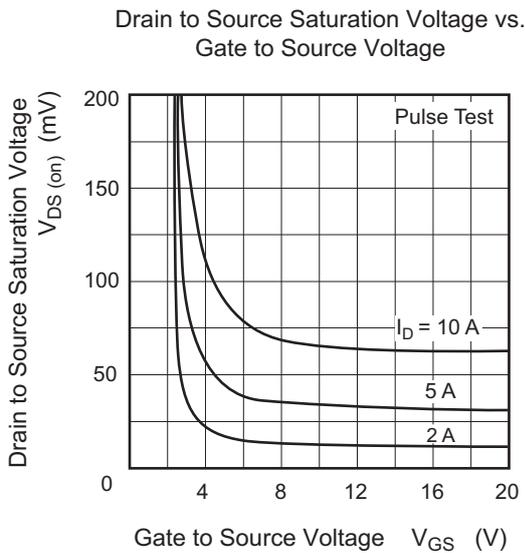
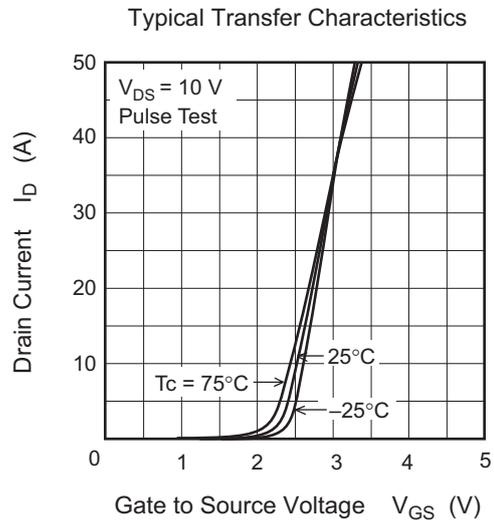
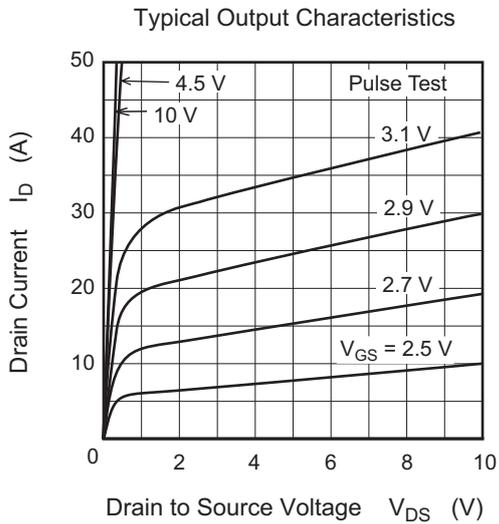
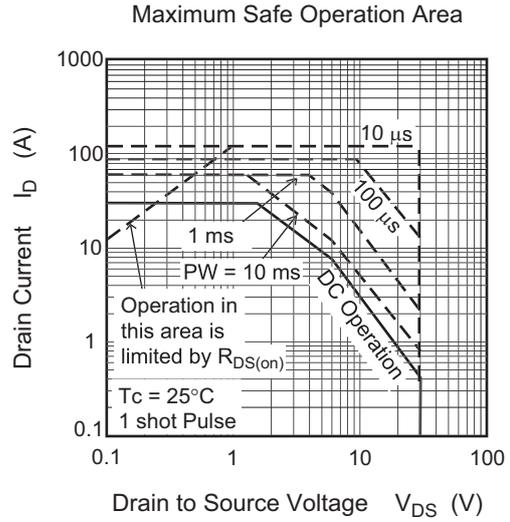
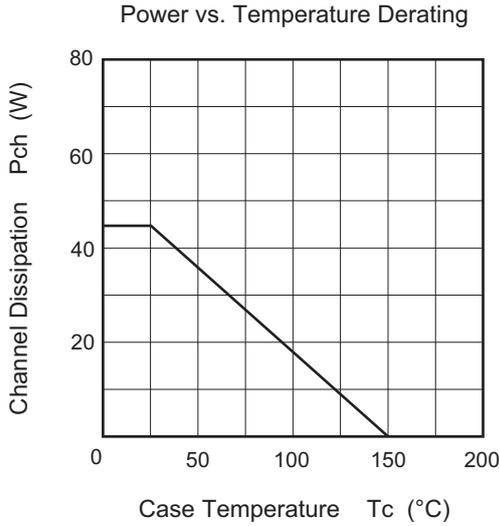
## Electrical Characteristics

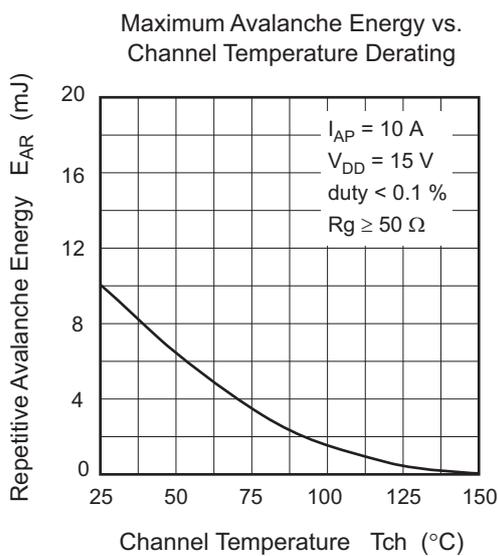
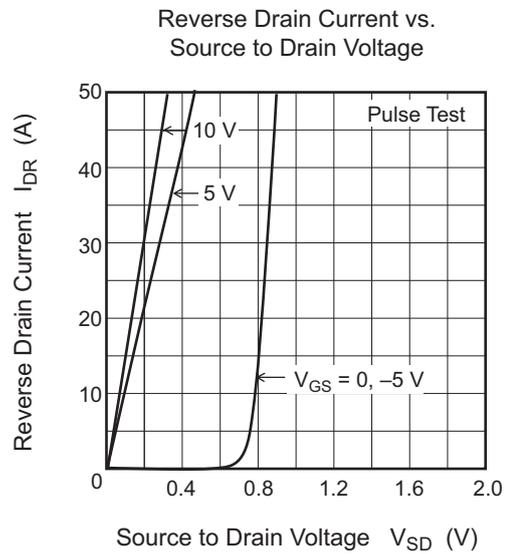
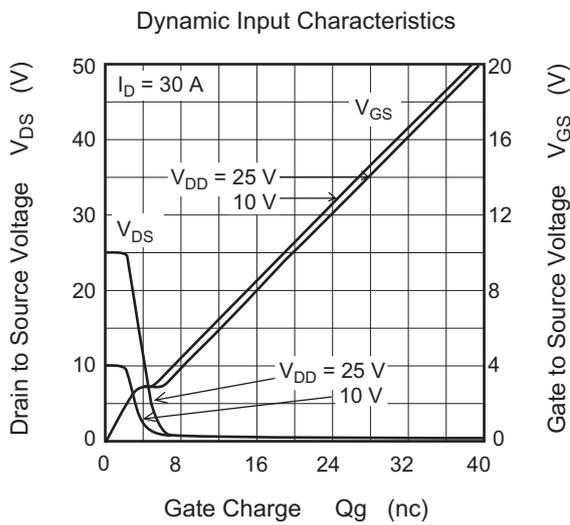
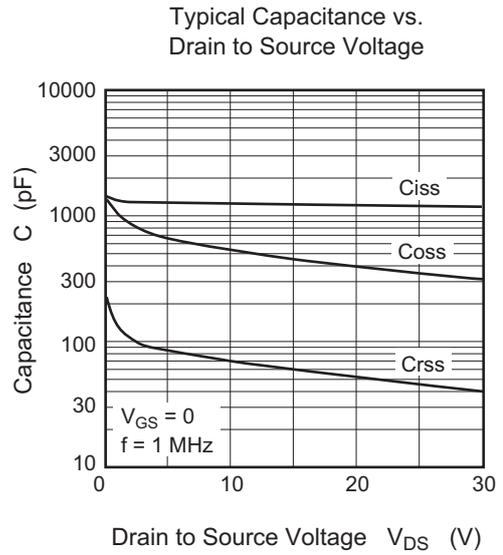
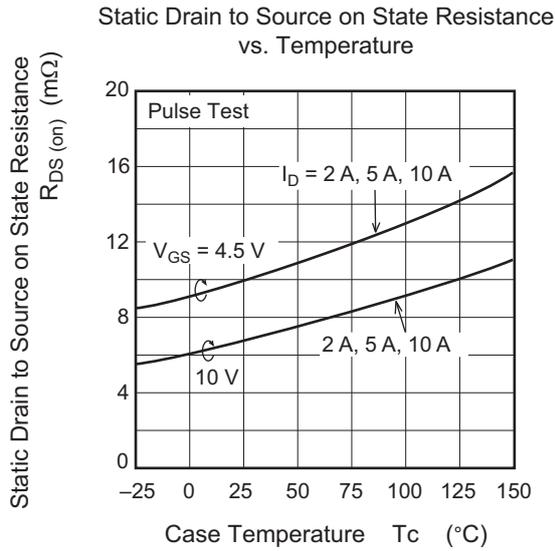
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = +16/-12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	6.7	8.0	$\text{m}\Omega$	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}$ <sup>Note4</sup>
	$R_{DS(on)}$	—	10	13	$\text{m}\Omega$	$I_D = 15 \text{ A}, V_{GS} = 4.5 \text{ V}$ <sup>Note4</sup>
Forward transfer admittance	$ y_{fs} $	—	45	—	S	$I_D = 15 \text{ A}, V_{DS} = 10 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	1250	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	530	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	70	—	pF	
Gate Resistance	$R_g$	—	0.6	—	$\Omega$	
Total gate charge	$Q_g$	—	8	—	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 30 \text{ A}$
Gate to source charge	$Q_{gs}$	—	3.6	—	nC	
Gate to drain charge	$Q_{gd}$	—	1.5	—	nC	
Turn-on delay time	$t_{d(on)}$	—	7.0	—	ns	$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A},$
Rise time	$t_r$	—	3.0	—	ns	$V_{DD} \cong 10 \text{ V}, R_L = 0.67 \Omega,$
Turn-off delay time	$t_{d(off)}$	—	35	—	ns	$R_g = 4.7 \Omega$
Fall time	$t_f$	—	3.0	—	ns	
Body-drain diode forward voltage	$V_{DF}$	—	0.85	1.08	V	$I_F = 30 \text{ A}, V_{GS} = 0$ <sup>Note4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	30	—	ns	$I_F = 30 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

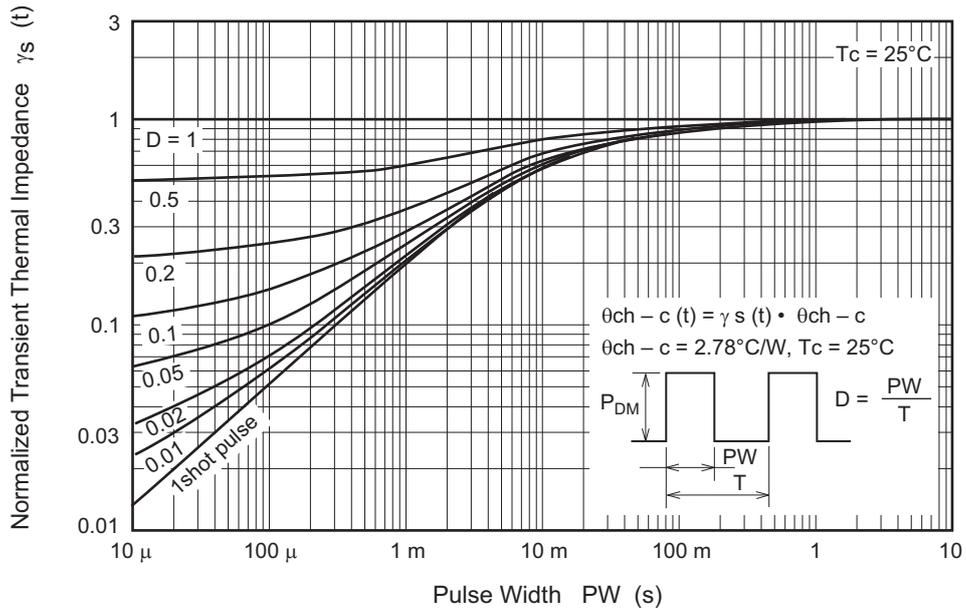
Notes: 4. Pulse test

Main Characteristics

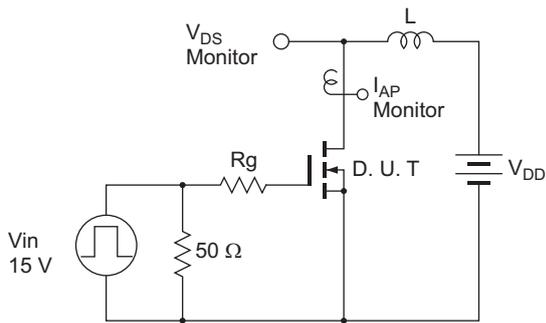




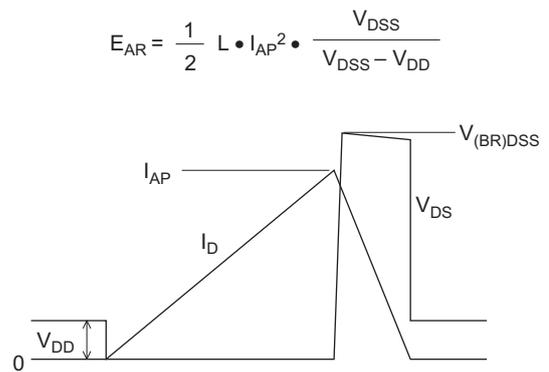
Normalized Transient Thermal Impedance vs. Pulse Width



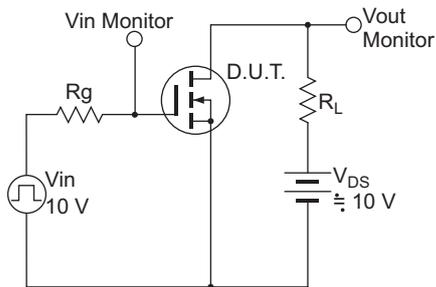
Avalanche Test Circuit



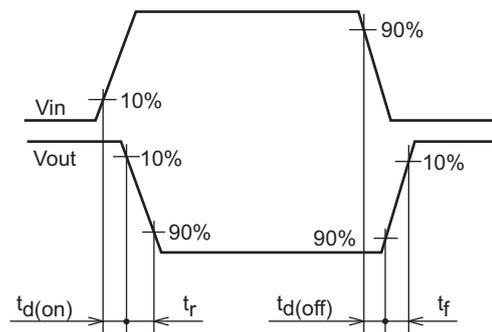
Avalanche Waveform



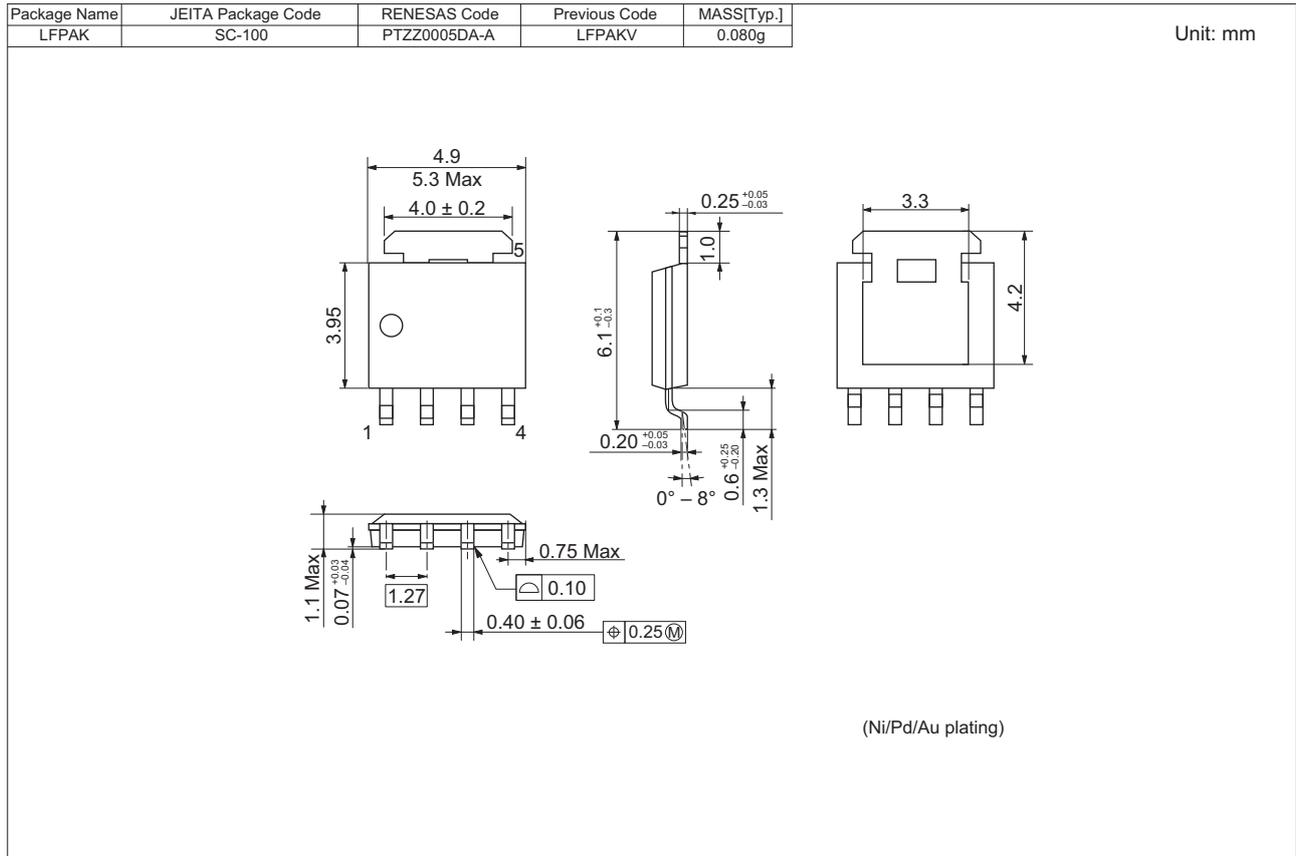
Switching Time Test Circuit



Switching Time Waveform



### Package Dimensions



### Ordering Information

Part Name	Quantity	Shipping Container
RJK0305DPB-02#J0	2500 pcs	Taping

Note: The symbol of "#" is occasionally presented as "-".

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